

PROGRAM

November 15 (Sunday)

16:00 – 19:00	Registration
18:00 – 20:00	Welcome (Mixer)

November 16 (Monday morning)

8:50 – 9:00	Opening	
9:00 – 9:35	Session A: J. O'Connor (Chair)	After silicon: structure and composition of high-k materials on novel substrates (Invited) <u>T. Gustafsson</u>
9:35 – 10:10		Beyond hafnia (Invited) <u>M. Copel</u>
10:10 – 10:30		The analysis of ultra-thin films with HRBS-30 <u>B. Brijs</u> , K. Kimura, H. Bender, W. Vandervorst
10:30 – 11:00	Coffee break	
11:00 – 11:35	Session B: T. Gustafsson (Chair)	Interface structures of metal oxide dielectrics and semiconductor nanocrystals (Invited) <u>L. Goncharova</u> , E.G. Barbagiovanni, T. Gustafsson
11:35 – 12:10		MEIS depth profiling of high-κ dielectrics for sub-45nm node CMOS applications (Invited) <u>P.R. Chalker</u> , M. Werner, T.C.Q. Noakes, P. Bailey
12:10 – 12:30		Extremely low energy SIMS for elemental quantification of ultrathin pedestal silicon-oxynitrides for high-κ devices <u>M. Py</u> , J.P. Barnes, O. Renault, F. Martin, R. Gassilloud
12:30 – 14:00	Lunch	

November 16 (Monday afternoon)

14:00 – 14:35	Session C: P. Woodruff (Chair)	High resolution medium energy ion scattering analysis for the quantitative depth profiling of ultra thin high-κ Hf based films (Invited) <u>J. van den Berg</u> , M.A. Reading, D.G. Armour, P. Bailey, T. Noakes, T. Conard, S. De Gendt
14:35 – 15:10		Surface and interface analysis with MEIS and LEEM/PEEM (Invited) <u>T. Koshikawa</u>
15:10 – 15:30		2-D analysis of hydrogen and oxygen maps on ion-implanted P and As in SiO₂ films <u>K. Ueda</u>
15:30 – 16:00	Coffee break	
16:00 – 16:35	Session D: S. Nakagawa (Chair)	Trajectory-dependent energy loss in MEIS from crystalline surfaces (Invited) A. Hentz, <u>D.P. Woodruff</u> , P.L. Grande, G. Schiwietz
16:35 – 17:10		Electronic energy-loss at small impact parameters – backscattering of H and He at intermediate velocities (Invited) <u>G. Schiwietz</u> , P.L. Grande
17:10 – 17:30		Characterization of nanoparticles through medium-energy ion scattering (MEIS): The influence of the asymmetrical lineshape M.A. Sortica, <u>P.L. Grande</u> , G. Machado, L. Miotti
17:30 – 17:50		The shower approach in the simulation of ion scattering from solids <u>V.A. Khodyrev</u> , R. Andrzejewski, D.O. Boerma, J.E. Prieto
18:30 – 20:30	Dinner	

November 17 (Tuesday morning)

8:45 – 9:20	Session E: T. Kaneko (Chair)	Classical and quantum rainbow scattering: interaction potentials and structure of surfaces (Invited) <u>H. Winter</u> , J. Seifert, M. Busch, S. Wethekam, A. Schüller
9:20 – 9:55		Electronic interactions of slow ions (Invited) <u>P. Bauer</u> , S.N. Markin, D. Primetzhofer, M. Spitz
9:55 – 10:15		Energy-loss straggling of helium projectiles at low kinetic energies <u>G. Anderson</u>
10:15 – 10:35		Determination of thickness of thin films from grazing scattering experiments <u>I.K. Gainullin</u> , D.K. Shestakov
10:35 – 11:00	Coffee break	
11:00 – 11:35	Session F: M. Copel (Chair)	High resolution depth profiling by laser assisted 3D atom probe (Invited) T. Ohkubo, Y.M. Chen, M. Kodzuka, F. Li, <u>K. Hono</u>
11:35 – 11:55		Laser-assisted three-dimensional atom probe analysis of dopant distribution at NiSi/Si Schottky junction <u>T. Kinno</u> , T. Ohkubo, Y. Nishi, T. Yamauchi, T. Marukame, K. Kato, M. Tomita, S. Takeno, K. Hono
11:55 – 12:15		Probing local adatom kinetics above a single surface site in the field ion microscope using a pulse counting analysis of field-ions <u>A. Kobayashi</u> , Y. Kamon, Y. Nakamura, K. Tanino, H. Kumagai
12:15 – 13:40	Lunch	

November 17 (Tuesday afternoon)

13:40 – 14:15	Session G: P. Bailey (Chair)	Cooled growth: influencing the structure of rare earth silicides on silicon (Invited) <u>S.P. Tear</u> , C. Eames, M. Reakes, T. Noakes, P. Bailey
14:15 – 14:50		Growth and transition of Fe on Pt(001) (Invited) <u>D.J. O'Connor</u> , D.A. McLaren, W. Allison, P.C. Dastoor, T.C.Q. Noakes
14:50 – 15:10		Surface relaxation at a stepped surface: a MEIS study of Cu(410)-O and Cu(100)-O D.C. Sheppard, <u>A. Hentz</u> , G.S. Parkinson, P.D. Quinn, M.A. Muñoz-Márquez, D.P. Woodruff
15:10 – 15:30		A medium energy ion scattering study of Pd thin film growth on Cu(111) <u>T.C.Q. Noakes</u> , P. Bailey, C.J. Howe, R.M. Wardle, T.P. Fleming, M.D. Cropper
15:30 – 16:00	Coffee break	
16:00 – 16:35	Session H: P.L. Grande (Chair)	Narrow nuclear resonance profiling and stable isotopic tracing study of the diffusion and reaction of carbon monoxide molecules in thermal silica and at its interface with silicon (Invited) <u>I. Vickridge</u> , M. D'Angelo, C.D. Cavellin, J.-J. Ganem, I. Trimaille, Y. Hoshino
16:35 – 16:55		Application of SiN membrane to hydrogen depth profiling in atmosphere by NRA via $^1\text{H}(^{15}\text{N},\alpha\gamma)^{12}\text{C}$ <u>H. Yonemura</u> , D. Sekiba, Y. Kitaoka, T. Narusawa, T. Ito, Y. Iwamura, K. Fukutani
16:55 – 17:15		Resonance depth profiles of Si/C/Si layers using narrow nuclear resonances of elastic proton backscattering $p + ^{12}\text{C}$ and $p + ^{28}\text{Si}$ <u>M. Tosaki</u> , K. Yasuda, R. Ishigami
18:00 – 20:00	Poster Session: (with Snack)	List of poster presentations is to be announced elsewhere.

November 18 (Wednesday)

8:45 – 9:20	Session I: S. Matsuyama (Chair)	Quantitative analysis of bio-interfaces with MEIS (Invited) <u>D.W. Moon</u>
9:20 – 9:55		A production of nano-beam with tapered glass capillaries and its application to living cell surgery (Invited) <u>Y. Yamazaki</u>
9:55 – 10:15		Secondary ion mass spectrometry depth profiling of organic films with large Ar cluster ion beams <u>S. Ninomiya</u> , K. Ichiki, H. Yamada, T. Seki, T. Aoki, J. Matsuo
10:15– 10:45	Coffee break	
10:45 – 11:20	Session J: L. Goncharova (Chair)	Sputter neutral mass spectrometry of surfaces from the NASA genesis mission (Invited) <u>B.V. King</u> , I.V. Veryovkin, C.E. Tripa, A.V. Zinovev, M.J. Pellin
11:20 – 11:55		Implanted solar wind oxygen about 4.6 billion years ago (Invited) <u>H. Yurimoto</u> , S. Itoh
12:00 –	Excursion (with Box Lunch) to Kiyomizu and Fushimi	
18:30 – 20:30	Banquet	

November 19 (Thursday)

8:45 – 9:20	Session K: P. Bauer (Chair)	Elastic recoil detection in the medium energy regime (Invited) <u>P. Bailey</u> , T. Noakes, C. Bonet, T. Wood
9:20 – 9:55		Quantitative ion beam analysis of ultra thin films with magnetic spectrometers using heavy MeV ions (Invited) <u>M. Kosmata</u> , R. Grötzschel, M. Vieluf, D. Hanf, F. Munnik, W. Möller
9:55 – 10:15		Ordering effects in extreme high-resolution depth profiling with MeV ion beams <u>H.J. Whitlow</u> , S.T. Nakagawa
10:15– 10:45	Coffee break	
10:45 – 11:20	Session L: H. Winter (Chair)	Spin polarization induced in organic thin films on ferromagnetic substrates (Invited) <u>Y. Yamauchi</u> , X. Sun, S. Entani, M. Kurahashi, T. Suzuki, Z.P. Wang
11:20 – 11:40		The growth of an ordered Mn layer on the Si(111)-1×1–Ho surface studied using MEIS and STM (Invited) <u>M.B. Reakes</u> , C. Eames, T.C.Q. Noakes, P. Bailey, S.P. Tear
11:40 – 12:00		High-resolution Channeling/RBS depth profiling of Sn implanted Si <u>T.K. Chan</u> , T. Osipowicz, A. Markwitz
12:00 – 12:10	Closing	
12:10 – or 12:30 –	Lunch or Post Conference Tour (with Box Lunch) to Mt. Hiei	